

2 N 3709	USA,Aeg,Tix	Si-N	=2N3708: hFE=45...165	7c	TO-92	BC 550	7a	BC 168, BC 183, BC 238, BC 548, ++	
2 N 3710	USA,Aeg,Tix	Si-N	=2N3708: hFE=90...330	7c	TO-92	BC 550	7a	BC 168, BC 183, BC 238, BC 548, ++	
2 N 3711	USA,Aeg,Tix	Si-N	=2N3708: hFE=180...600	7c	TO-92	BC 550	7a	BC 168, BC 183, BC 238, BC 548, ++	
2 N 3712(S)	USA,Mot,Tix	Si-N	Vid, 150/150V, 0,2A, 1W, >40MHz	(S: TO-39	2a	TO-5	2a	BF 257...259, BF 657...759, 2N5058...59, ++	
2 N 3713	USA,Mot,Sgs	Si-N	LFS P, 80/60V, 10/15A, 150W, >4MHz, hFE=25...90	23a	TO-3	BD 317	23a	BD 545B, BD 315, 2N3772, 2N5632...34, ++	
	Tos,Tix,++		450/350ns	(2N3789					
2 N 3714		Si-N	=2N3713: 100/80V	(2N3790	23a	TO-3	BD 317	23a	BD 545C, BD 317, 2N3772, 2N5632...34, ++
2 N 3715		Si-N	=2N3713: hFE=50...150	(2N3791	23a	TO-3	BD 317	23a	BD 545B, BD 315, 2N3772, 2N5632...34, ++
2 N 3716		Si-N	=2N3713: 100/80V, hFE=50...150	(2N3792	23a	TO-3	BD 317	23a	BD 545C, BD 317, 2N3772, 2N5632...34, ++
2 N 3717	Mot	Si-N	HF/S, 60V, 1A, 7,5W(Tc=25°), 250MHz	2a	TO-39			2N3553, 2SC2419	
2 N 3718	Mot	Si-N	HF/S, 60V, 1A, 10W(Tc=25°), 250MHz	49a				BLY 60	
2 N 3719	USA,Mot,Tix	Si-P	S, 40V, 3A, 1W, >60MHz, <100/400ns	2a	TO-5			2N3867...68, 2N6303	
2 N 3720	USA,Mot,Tix	Si-P	=2N3719: 60V	2a	TO-5			2N3868, 2N6303	
2 N 3721	USA,Gen,Mic	Si-N	Uni, 18V, 0,1A, 0,36W, 120MHz	7c	TO-98			BC 168, BC 183, BC238, BC 548, ++	
2 N 3722	USA,Mot	Si-N	S, 80V, 0,5A, 0,8W, >300MHz, <62/130ns	2a	TO-5			BSV 95, 2N3725, 2SC1069	
2 N 3723	USA,Mot	Si-N	=2N3722: 100V, <85/160ns	2a	TO-5			BSW 39, 2SC1069	
2 N 3724	USA,Fer,Itt	Si-N	S, 50/30V, 0,5A, 0,8W, >300MHz, 20/55ns, hFE>60	2a	TO-39			BSV 77, BSV 95, 2N3722...23, 2N5189, ++	
	Mot,Sgs,Tix			(2N3467					
2 N 3724 A		Si-N	=2N3724: 1,2A, 2W	2a	TO-39			BSS 14, 2N3734...35, 2N5262	
2 N 3725	=2N3724	Si-N	=2N3724: 80/50V	(2N3468	2a	TO-39		BSV 95, 2N3722...23, 2SC1069	
2 N 3725 A		Si-N	=2N3725: 1,2A	2a	TO-39			BSS 14, 2N3735, 2N5262	
2 N 3726	USA,Fch,Mic	Si-P	Dual, in, 45/45V, 0,3A, 0,5W, >200MHz, <4dB(1kHz)	TO-77	(CBE-EBC-)			2N4015...4016	
	Mot,Sgs,++		hFE=135...350, ΔhFE=0,9...1, ΔUbe<5mV						
2 N 3727	=2N3727	Si-P	ΔUbe<2,5mV	TO-77	(CBE-EBC-)			2N4015...4016	
2 N 3728	Fch,Ray,Sca	Si-N	Dual, 60/30V, 0,5A, 0,45W, >80MHz, F<7dB(1kHz)	TO-77	(CBE-EBC-)			BFX 70...72, 2N2060, 2N2223	
	Sgs		hFE=80...280, ΔhFE=0,8...1, ΔUbe<5mV						
2 N 3729	=2N3728	Si-N	=2N3728: ΔhFE=0,9...1, ΔUbe<3mV	TO-77	(CBE-EBC-)			BFX 70...72, 2N2060, 2N2223	
2 N 3730	Gpd,Rca	Ge-P	TV-HA, 200V, 3A, 10W(Tc=55°)	23a	TO-3			AU 107, AU 113, AU 213, 2N5324	
2 N 3731	Gpd,Rca	Ge-P	TV-HA, 320V, -/10A, 5W(Tc=55°)	23a	TO-3			AU 106, AU 109, AU 111...112, 2N5325	
2 N 3732	Gpd,Rca	Ge-P	TV-HA, 100V, 3A, 3W(Tc=55°)	23a	TO-3			AU 108, AU 110, AU 210	
2 N 3733	USA,EUR	Si-N	VHF/UHF P, 65V, 3A, PQ>10W(400MHz)	49a	TO-60			-	
2 N 3734(S)		Si-N	S,Drv, 50V, 1,5A, 1W, >250MHz, <48/60ns	2a	TO-5			BSS 14, 2N5262	
2 N 3735(S)	USA,EUR	Si-N	=2N3734: 75V	2a	TO-5			BSS 14, 2N5262	
2 N 3736	USA,EUR	Si-N	=2N3734: 0,5W	2a	TO-46			-	
2 N 3737		Si-N	=2N3734: 75V, 0,5W	2a	TO-46			-	
2 N 3738	USA,Mot,Tho	Si-N	LFS P, 250/225V, 1A, 20W, >10MHz	(2N6424	22a	TO-66		BUW 40(A,B), BUX 84, 2N4296...97, ++	
2 N 3739	USA,Mot,Tho	Si-N	=2N3738: 325/300V	(2N6425	22a	TO-66		BUW 40(A,B), BUX 84, 2N4296...97, ++	
2 N 3740(A)	USA,Fch,Mot	Si-P	LFS P, 60/60V, 4/10A, 25W, >4MHz, hFE=30...100	22a	TO-66	BD 244 C	17j	BD 244A, BD 540A, BDX 14, 2N6313...14, ++	
	Sgs,Tho,Tix		Ir<100μA(A: <0,1μA)(Umax)	(2N3766					
2 N 3741(A)	=2N3740	Si-P	=2N3740: 80/80V	(2N3767	22a	TO-66	BD 244 C	17j	BD 244B, BD 540B, BDX 14, 2N6314, ++
2 N 3742(S)	Mot,Nsc,Sca	Si-N	Vid, 300/300V, 0,05A, 1W, >30MHz, hFE=20...200	2a	TO-5	MPS-U10 <sup>6</sup>	13m	BF 259, BF 659, BFR 59, BFS 89, 2N5058	
	Ssi,Stc		2N3742S: TO-39	(2N3743					
2 N 3743(S)	Mot,Nsc,Sca	Si-P	Vid, 300/300V, 0,05A, 1W, >30MHz, hFE=25...250	2a	TO-5	MPS-U60	13m	BFT 44, BFQ 37, 2SB622	
	Ssi,Stc		2N3743S: TO-39	(2N3742					
2 N 3744	USA,Tix	Si-N	S P, 60V, 5A, 30W(Tc=100°), >30MHz, hFE=20...60	50g	TO-111			-	
2 N 3745		Si-N	=2N3744: 80V	50g	TO-111			-	
2 N 3746		Si-N	=2N3744: 100V	50g	TO-111			-	
2 N 3747	USA,Tix	Si-N	S P, 60V, 5A, 30W(Tc=100°), >40MHz, hFE=40...120	50g	TO-111			-	
2 N 3748		Si-N	=2N3747: 80V	50g	TO-111			-	
2 N 3749		Si-N	=2N3747: 100V	50g	TO-111			-	
2 N 3750	USA,Tix	Si-N	S P, 60V, 5A, 30W(Tc=100°), >50MHz, hFE=100...300	50g	TO-111			-	
2 N 3751		Si-N	=2N3750: 80V	50g	TO-111			-	
2 N 3752		Si-N	=2N3750: 100V	50g	TO-111			-	
2 N 3762(S)	USA,Mot	Si-P	S,Drv, 40V, 1,5A, 1W, >180MHz, <43/115ns	2a	TO-5			BSV 82, 2SA799	
2 N 3763(S)		Si-P	=2N3762: 60V	2a	TO-5			BSV 82, 2SA799	
2 N 3764(A)		Si-P	=2N3762: 0,5W	2a	TO-46			-	
2 N 3765		Si-P	=2N3762: 60V, 0,5W	2a	TO-46			-	
2 N 3766	USA,Fch,Mot	Si-N	LFS P, 80/60V, 4/4A, 20W, >10MHz, hFE=40...160	22a	TO-66			BD 243B, BD 539B, BD 951, 2N3054, ++	
	Sgs,Tix			(2N3740					
2 N 3767		Si-N	=2N3766: 100/80V	(2N3741	22a	TO-66		BD 243C, BD 539C, BD 953, 2N3054, ++	
2 N 3770	Spr	Ge-P	HF, 10V, 0,05A, 0,05W, >100MHz	2a	TO-18			AF 106, AF 109R, AF 306, 2N3323...25	
2 N 3771	USA,EUR,Tos	Si-N	LFS P, 50/40V, 30/30A, 150W, >0,2MHz	23a	TO-3			BDX 41, BDY 29, MJ 802, 2SD630...631	
2 N 3772	USA,EUR,Tos	Si-N	LFS P, 100/60V, 20/30A, 150W, >0,2MHz	23a	TO-3			BDX 40, BDY 29, MJ 802, 2SD797	
2 N 3773	USA,EUR,Tos	Si-N	LFS P, 160/140V, 16/30A, 150W, >0,2MHz	(2N6609	23a	TO-3	MJ 15015	23a	BDW 32...36, BDX 50, MJ 15015, 2SC2608
2 N 3774	USA,Tix	Si-P	LFS, 40/40V, 1A, 5W(Tc=100°), >1MHz, hFE=20...60	2a	TO-5			BSS 17...18, BSW 40, BSV 82, 2N5322...23	
2 N 3775		Si-P	=2N3774: 60/60V	2a	TO-5			BSS 17...18, BSW 40, BSV 82, 2N5322...23	
2 N 3776		Si-P	=2N3774: 80/80V	2a	TO-5			BSS 17...18, BSW 40, BSV 82, 2N5322...23	
2 N 3777		Si-P	=2N3774: 100/100V	2a	TO-5			BSS 17, BSW 40, 2N5322	
2 N 3778	USA,Tix	Si-P	=2N3774: hFE=10...40	2a	TO-5			BSS 17...18, BSW 40, BSV 82, 2N5322...23	
2 N 3779		Si-P	=2N3774: 60/60V, hFE=10...40	2a	TO-5			BSS 17...18, BSW 40, BSV 82, 2N5322...23	
2 N 3780		Si-P	=2N3774: 80/80V, hFE=10...40	2a	TO-5			BSS 17...18, BSW 40, BSV 82, 2N5322...23	
2 N 3781		Si-P	=2N3774: 100/100V, hFE=10...40	2a	TO-5			BSS 17, BSW 40, 2N5322	
2 N 3782	USA,Tix	Si-P	=2N3774: 3A, hFE=10...60	2a	TO-5			2N3719...20, 2N3867...68, 2N4234...36	
2 N 3783	Mot,Ssi	Ge-P	UHF, 30V, 0,02A, 0,15W, >800MHz	5g	TO-72			AF 139, AF 239(S), 2N3279...86	
2 N 3784	Mot,Ssi	Ge-P	UHF, 30V, 0,02A, 0,15W, >700MHz	5g	TO-72			AF 139, AF 239(S), 2N3279...86	
2 N 3785	Mot,Ssi	Ge-P	UHF, 15V, 0,02A, 0,15W, >700MHz	5g	TO-72			AF 139, AF 239(S), 2N3279...86	
2 N 3788	Sol,Ssi,Stc	Si-N	TV-HA, 400/325V, 2A, 100W	23a	TO-3			BU 104, BU 606, BU 608	
2 N 3789	USA,Mot,Sgs	Si-P	LFS P, 60/60V, 10/15A, 150W, >4MHz, hFE=25...90	23a	TO-3	BD 318	23a	BD546A, BD316, 2N6029...31, 2N6229...31, ++	
	Tix,Tos,++		350/800ns	(2N3713					
2 N 3790		Si-P	=2N3789: 80/80V	(2N3714	23a	TO-3	BD 318	23a	BD546B, BD318, 2N6029...31, 2N6229...31, ++
2 N 3791		Si-P	=2N3789: hFE=50...150	(2N3715	23a	TO-3	BD 318	23a	BD546A, BD316, 2N6029...31, 2N6229...31, ++
2 N 3792		Si-P	=2N3789: 80/80V, hFE=50...150	(2N3716	23a	TO-3	BD 318	23a	BD546B, BD318, 2N6029...31, 2N6229...31, ++
2 N 3793	USA,Mic,Phi	Si-N	LF, 40V, 0,3A, 0,25W, 220MHz, hFE=20...150	=40b				BC 337, BC 635, BC 637, BC 639, ++	
2 N 3794		Si-N	=2N3793: 100MHz, hFE=100...600	=40b				BC 337, BC 635, BC 637, BC 639, ++	
2 N 3795	Csr,Ssi,Stc	Si-P	LFS, 120V, 1A, 5W(Tc=25°), >0,5MHz, <5/5μs	2a	TO-5			2N3634...37, 2N5415	
2 N 3796	Mot	MOS-N-FET-d	LF, 30V, Idss>0,5mA, Up<4V	2a	TO-18			-	
2 N 3797	Mot	MOS-N-FET-d	LF, 30V, Idss>2mA, Up<7V	2a	TO-18			-	
2 N 3798	USA,Mot,Tix	Si-P	Uni, in, 60V, 0,05A, 0,36W, >100MHz, hFE=150...450	2a	TO-18			2SA872(A), 2SA941...942, 2SA970, ++	
2 N 3798 A		Si-P	=2N3798: 90V	2a	TO-18			2SA872(A), 2SA941...942, 2SA970, ++	
2 N 3799		Si-P	=2N3798: hFE=300...900	2a	TO-18			2SA872(A), 2SA941...942, 2SA970, ++	
2 N 3799 A		Si-P	=2N3798: 90V, hFE=300...900	2a	TO-18			2SA872(A), 2SA941...942, 2SA970, ++	
2 N 3800	Fch,Mot,Nsc	Si-P	Dual, in, 60/60V, 0,05A, 0,36W, >100MHz, F<3dB(1k)	TO-71	(EBC-EBC-)			-	
	Ray		hFE=150...450, ΔhFE=, ΔUbe=						